UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/526,999	03/07/2005	Yuichiro Sasaki	NGB-8675US	9408
23122 7590 07/09/2007 RATNERPRESTIA P O BOX 980			EXAMINER	
			SARKAR, ASOK K	
VALLEY FOR	GE, PA 19482-0980		ART UNIT	PAPER NUMBER
			2891	
•				·
			MAIL DATE	DELIVERY MODE
			07/09/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

		TH			
	Application No.	Applicant(s)			
	10/526,999	SASAKI ET AL.			
Office Action Summary	Examiner	Art Unit			
	Asok K. Sarkar	2891			
The MAILING DATE of this communication ap Period for Reply	ppears on the cover sheet w	ith the correspondence address			
A SHORTENED STATUTORY PERIOD FOR REPI WHICHEVER IS LONGER, FROM THE MAILING I  - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory period  - Failure to reply within the set or extended period for reply will, by statu Any reply received by the Office later than three months after the maili earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUN .136(a). In no event, however, may a d will apply and will expire SIX (6) MO tte, cause the application to become A	CATION. reply be timely filed  NTHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 18.	June 2007.				
2a) ☐ This action is <b>FINAL</b> . 2b) ☑ Th					
3) Since this application is in condition for allow	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is				
closed in accordance with the practice under	Ex parte Quayle, 1935 C.	). 11, 453 O.G. 213.			
Disposition of Claims					
4) Claim(s) 1-50 is/are pending in the applicatio	n.				
4a) Of the above claim(s) 18-33 is/are withdra	awn from consideration.				
5) Claim(s) is/are allowed.					
6)⊠ Claim(s) <u>1-17 and 34-50</u> is/are rejected.					
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and	or election requirement.				
Application Papers					
9) The specification is objected to by the Examir	ner.				
10)⊠ The drawing(s) filed on <u>07 March 2005</u> is/are:					
Applicant may not request that any objection to th					
Replacement drawing sheet(s) including the corre					
11) The oath or declaration is objected to by the E	Examiner. Note the attache	d Office Action or form PTO-152.			
Priority under 35 U.S.C. § 119		·			
12) Acknowledgment is made of a claim for foreigna) All b) Some * c) None of:		§ 119(a)-(d) or (f).			
<ul><li>1. Certified copies of the priority document</li><li>2. Certified copies of the priority document</li></ul>		Application No			
3. Copies of the certified copies of the pri					
application from the International Bure					
* See the attached detailed Office action for a lis		t received.			
Attachment(s)					
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)		Summary (PTO-413) (s)/Mail Date			
3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date 3/7/05.		Informal Patent Application			

Application/Control Number: 10/526,999 Page 2

Art Unit: 2891

# **DETAILED ACTION**

#### Election/Restrictions

1. Applicant's election with traverse of Group I claims 1 – 17 and 34 – 50 in the reply filed on June 18, 2007 is acknowledged. The traversal is on the ground(s) that claim 50 has been omitted from the requirement. However, upon discovering the omission, the claim 50 was placed in Group I and was examined with the elected claims. Since, the Applicant did not have any other objection to the restriction, the reasons for the traversal is not found to be persuasive.

The requirement is still deemed proper and is therefore made FINAL.

### Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 3. Claims 1 3, 6, 10 13, 16, 17, 34 36, 39, 43 46, 49 and 50 are rejected under 35 U.S.C. 102(b) as being anticipated by Mizuno, US 5,851,906.

Regarding claim 1, Mizuno teaches a method of introducing impurity; wherein,

in the course of introducing a material to a solid substance (see the Title) which
has an oxidized film or other film sticking on the surface, the oxidized film and
other film are first removed as the surface treatment to the solid substance with
at least one means selected from among the group consisting of a means for
irradiating the surface of solid substance with plasma, a means for irradiating the

surface of solid substance with gas and a means for dipping the surface of solid substance in a reductive liquid in column 1, lines 15 - 20 and in column 3, lines 47 - 67, and

then a certain desired particle is attached or introduced in column 4, lines 4 – 23.
 Regarding claim 2, Mizuno teaches the plasma is that of a rare argon gas, or a system containing hydrogen in column 3, lines 51 – 55.

Regarding claim 3, Mizuno teaches the gas is that of a system containing Hydrogen in column 1, lines 15 - 20.

Regarding claim 6, Mizuno teaches the certain desired particle is attached or introduced by bringing a gas containing the certain desired particle to make contact to the surface of solid substance which surface has been made to be free of the oxidized film and other film, thereby the particle is attached or introduced to the surface, or the vicinity, of solid substance as was described earlier in rejecting claim 1 and in column 4, lines 4-23.

Regarding claim 10, Mizuno teaches the attaching or introducing of a certain desired particle is conducted in an environment in which the temperature of solid substance is lower than 600 °C in column 4, lines 22 – 23.

Regarding claim 11, Mizuno teaches a method of introducing impurity; wherein, in the course of introducing a material in the phase of ion, plasma, gas, etc. to a solid substance which has an oxidized film or other film sticking to the surface, the oxidized film and other film are first removed as the surface treatment to solid substance with at least one means selected from among the group consisting of a means for irradiating

Page 4

Art Unit: 2891

the surface of solid substance with plasma, a means for irradiating the surface of solid substance with gas and a means for dipping the surface of solid substance in a reductive liquid, and then a certain desired particle is attached or introduced as was described earlier in rejecting claim 1.

Regarding claim 12, Mizuno teaches the certain desired particle is attached or introduced while it is in the state of gas in column 4, lines 10 - 15.

Regarding claims 13, 16 and 49 Mizuno teaches at least one facility selected from among each of the following respective categories is used; at least one apparatus selected from among the group consisting of an apparatus for irradiating the surface of solid substance with plasma, an apparatus for irradiating the surface of solid substance with gas and an apparatus for dipping the surface of solid substance in a reductive liquid; an apparatus for bringing a gas containing a certain desired particle to the surface of solid substance; and an annealing apparatus for diffusing the certain desired particle attached or introduced therein with reference to Fig. 1 and in between column 3, line 34 and column 4, line 56.

Regarding claims 17 and 50, Mizuno teaches the limitations of the claim as were described earlier in rejecting claims 1 and 11.

Regarding claims 34 - 36, Mizuno teaches the limitations of the claims as were described earlier in rejecting claims 1 - 3.

Regarding claim 39, Mizuno teaches the limitations of the claim as were described earlier in rejecting claims 11 and 13.

Regarding claim 43, Mizuno teaches the limitations of the claim as were described earlier in rejecting claim 10.

Regarding claims 44 - 46, Mizuno teaches the limitations of the claims as were described earlier in rejecting claims 11 - 13.

## Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. The factual inquiries set forth in *Graham* v. *John Deere Co.*, 383 U.S. 1, 148 USPQ 459 (1966), that are applied for establishing a background for determining obviousness under 35 U.S.C. 103(a) are summarized as follows:
  - 1. Determining the scope and contents of the prior art.
  - 2. Ascertaining the differences between the prior art and the claims at issue.
  - 3. Resolving the level of ordinary skill in the pertinent art.
  - 4. Considering objective evidence present in the application indicating obviousness or nonobviousness.
- 6. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to

consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

7. Claims 4, 5, 14, 15, 37, 38 and 47 are rejected under 35 U.S.C. 103(a) as being unpatentable over Mizuno, US 5,851,906 in view of Hymes, US 6,324,715.

Mizuno <u>fails</u> to teach a means for dipping the surface of solid substance in a reductive liquid, and the reductive liquid is at least one item selected from among the group consisting of hydrogen fluoride, sodium hydroxide, aqueous ammonia, sulfinic acid and adipic acid di-2-ethylhexyl ester, etc. and the means for dipping the surface of solid substance in a reductive liquid rubs the surface of solid substance mechanically when it is dipped in the reductive liquid.

Hymes teaches an apparatus for cleaning the surface of a silicon wafer by dipping and scrubbing with a liquid containing aqueous ammonia and hydrogen fluoride in column 5, lines 10 - 20 and throughout the disclosure for the benefit of converting the hydrophobic surface to a hydrophilic surface in column 2, lines 34 - 42.

Therefore, it would have been obvious to one with ordinary skill in the art at the time of the invention to modify Mizuno and clean the surface of a silicon wafer by dipping and scrubbing with a liquid containing aqueous ammonia and hydrogen fluoride for the benefit of converting the hydrophobic surface to a hydrophilic surface as taught by Hymes in column 2, lines 34 – 42.

8. Claims 7 – 9, 40 – 42 and 48 are rejected under 35 U.S.C. 103(a) as being unpatentable over Mizuno, US 5,851,906 in view of NTT Corp., JP 07094427 (English Abstract and Translation).

Regarding claims 7, 40 and 48, Mizuno <u>fails</u> to teach the method of attaching or introducing a certain desired particle is irradiating the surface of solid substance, which surface has been made to be free of the oxidized film and other film, with electromagnetic wave whose energy is matching the energy that is binding the hydrogen or hydroxyl radical sticking on the surface with the atom of solid substance, thereby converting the binding into a non – coupled state, separating the sticking hydrogen or hydroxyl radical, and exposing the atom constituting solid substance to the surface; and then introducing the certain desired particle for making contact so that the particle is attached or introduced to the surface, or the vicinity, of solid substance.

NTT Corp teaches a method of doping in which the surface of solid substance is irradiated with an electromagnetic wave at an energy that is more than the ionization energy of the doping gas (see the English Abstract). This energy should be sufficient to separate the sticking hydrogen or hydroxyl radical from the oxide removal process, and expose the atom constituting solid substance to the surface so that the particle is attached or introduced to the surface, or the vicinity, of solid substance after making the contact with the surface for the benefit of doping at low temperature of 400 °C or less (see the Advantage in the English Abstract, also paragraph 9 of the English translation).

Therefore, it would have been obvious to one with ordinary skill in the art at the time of the invention to modify Mizuno and irradiate the surface of solid substance, which surface has been made to be free of the oxidized film and other film, with electromagnetic wave whose energy matches the energy that is binding the hydrogen or hydroxyl radical sticking on the surface with the atom of solid substance, thereby

converting the binding into a non – coupled state, separating the sticking hydrogen or hydroxyl radical, and exposing the atom constituting solid substance to the surface; and then introducing the certain desired particle for making contact so that the particle is attached or introduced to the surface, or the vicinity, of solid substance for the benefit of doping at low temperature of 400 °C or less as taught by NTT Corp in the Advantage portion of the English Abstract and in paragraph 9 of the English translation.

Regarding claims 8, 9, 41 and 42, Mizuno <u>fails</u> to teach the energy of irradiating electromagnetic wave is between 318 kJ/mol and 666 kJ/mol.

However, it would have been obvious to one with ordinary skill in the art at the time of the invention to judiciously adjust and control these parameters during the doping process of the NTT Corp. through routine experimentation and optimization to achieve optimum benefits (see MPEP 2144.05) and it would not yield any unexpected results.

Note that the specification contains no disclosure of either the critical nature of the claimed processes or any unexpected results arising therefrom. Where patentability is said to be based upon particular chosen methods or upon another variable recited in a claim, the Applicant must show that the chosen methods or variables are critical (*Woodruff*, 919 F.2d 1575, 1578, 16 USPQ2d 1934, 1936 (Fed. Cir., 1990)). See also *In re Aller, Lacey and Hall* (10 USPQ 233 – 237).

Application/Control Number: 10/526,999 Page 9

Art Unit: 2891

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Asok K. Sarkar whose telephone number is 571 272 1970. The examiner can normally be reached on Monday - Friday (8 AM- 5 PM).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, William B. Baumeister can be reached on 571 272 1722. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Asok K. Sarkar July 3, 2007

Primary Examiner